National Semiconductor

Comlinear CLC109
Low-Power, Wideband, Closed-Loop Buffer

General Description

The Comlinear CLC109 is a high-performance, closed-loop monolithic buffer intended for power sensitive applications. Requiring only 35mW of quiescent power (±5V supplies), the CLC109 offers a high bandwidth of 270MHz (0.5V_{pp}) and a slew rate of 350V/µs. Even with this minimal dissipation, the CLC109 can easily drive a demanding 100Ω load. The buffer specifications are for a 100Ω load.

With its patented closed-loop topology, the CLC109 has significant performance advantages over conventional open-loop designs. Applications requiring low (2.8Ω) output impedance and nearly ideal unity gain (0.997) through very high frequencies will benefit from the CLC109's superior performance. Power sensitive applications will benefit from the CLC109's excellent performance on reduced or single supply voltages.

Constructed using an advanced, complementary bipolar process and Comlinear's proven high-performance architectures, the CLC109 is available in several versions to meet a variety of requirements.

CLC109AJP	-40°C to +85°C	8-pin Plastic DIP
CLC109AJE	-40°C to +85°C	8-pin Plastic SOIC
CLC109A8B	-55°C to +125°C	8-pin hermetic CERDIP, MIL-STD-883, Level B
CLC109ALC	-40°C to +85°C	dice
CLC109AMC	-55°C to +125°C	dice qualified to Method 5008, MIL-STD-883, Level B

Contact factory for other packages and DESC SMD number.

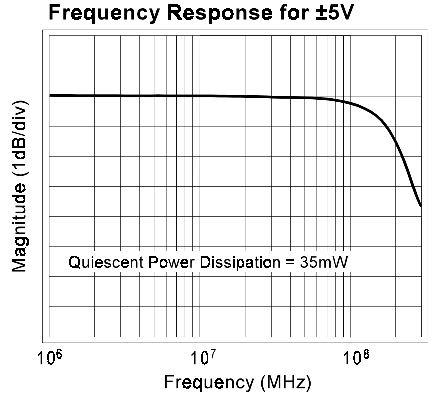
Features

- High small-signal bandwidth (270MHz)
- Low supply current (3.5mA @ ±5V)
- Low output impedance (2.8Ω)
- 350V/µs slew rate
- Single supply operation (0 to 3V supply min.)
- Evaluation boards and Spice models

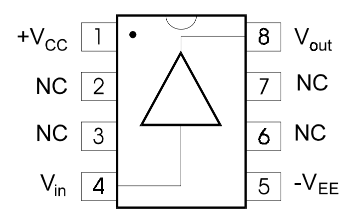
Applications

- Video switch buffers
- Test point drivers
- Low power active filters
- DC clamping buffer
- High-speed S & H circuits
- Inverting op amp input buffer

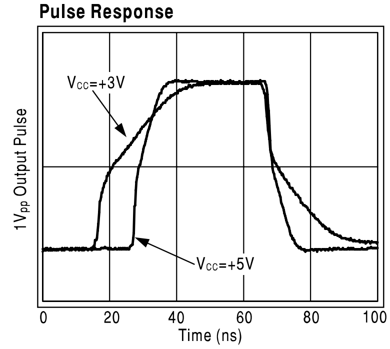
Frequency Response for ±5V



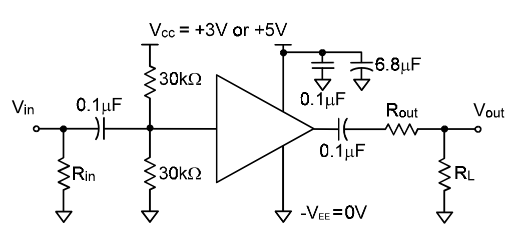
PINOUT
DIP & SOIC



Pulse Response

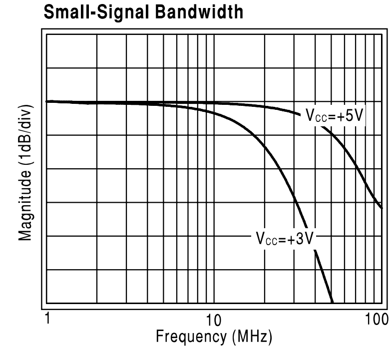


Typical Application



Single-Supply Circuit

Small-Signal Bandwidth



CLC109 Electrical Characteristics (±V_{cc} = ± 5V, R_L = 100Ω unless specified)

PARAMETER	CONDITIONS	TYP	MIN/MAX RATINGS			UNITS	SYMBOL
Ambient Temperature	CLC109AJ/AI	+25°C	-40°C	+25°C	+85°C		
	CLC109A8/AM/AL	+25°C	-55°C	+25°C	+125°C		
FREQUENCY RESPONSE							
†small signal bandwidth	V_{out} < 0.5V_{pp}	270	200	200	150	MHz	SSBW
	V_{out} < 2.0V_{pp}	120	90	90	70	MHz	LSBW
gain flatness[1]	V_{out} < 0.5V_{pp}						
†flatness	DC-30MHz	0	±0.1	±0.1	±0.1	dB	GFL
†peaking	DC-200MHz	0	1.0	0.3	0.3	dB	GFPH
†rolloff DC-60MHz	0.1	0.4	0.4	0.6	dB	GFRH	
differential gain	4.43MHz, 150Ω load	0.7	1.5	1.0	1.0	%	DG
differential phase	4.43MHz, 150Ω load	0.03	0.05	0.05	0.1	°	DP
TIME DOMAIN RESPONSE							
rise and fall time	0.5V step	1.3	1.7	1.7	2.3	ns	TRS
	2.0V step	4.4	6	6	7	ns	TRL
settling time to ±0.05%	2.0V step	12	25	18	25	ns	TS
overshoot	0.5V step	3	15	10	10	%	OS1
slew rate	4V step	350	220	250	220	V/µsec	SR
DISTORTION AND NOISE PERFORMANCE							
†2nd harmonic distortion	2V_{pp}, 20MHz	-46	-36	-38	-38	dBc	HD2
†3rd harmonic distortion	2V_{pp}, 20MHz	-55	-50	-50	-45	dBc	HD3
equivalent output noise							
voltage		3.3	4.1	4.1	4.5	nV/√Hz	VN
current		1.3	3	2	2	pA/√Hz	ICN
STATIC DC PERFORMANCE							
small signal gain	no load	0.997	0.995	0.995	0.994	V/V	GA1
	100Ω load	0.96	0.94	0.95	0.95	V/V	GA2
output resistance	DC	2.8	5.0	4.0	4.0	Ω	RO
*output offset voltage		1	±8.2	±5	±6	mV	VIO
average temperature coefficient		±10	±40		±30	µV/°C	DVIO
*input bias current		±2	±8	±4	±4	µA	IBN
average temperature coefficient		±30	±50		±25	nA/°C	DIBN
†power supply rejection ratio		-56	-48	-48	-46	dB	PSRR
*supply current	no load	3.5	4	4	4	mA	ICC
MISCELLANEOUS PERFORMANCE							
integral endpoint linearity	±1V, full scale	0.5	1.0	0.7	0.6	%	ILIN
input resistance		1.5	0.3	1.0	2.0	MΩ	RIN
input capacitance	CERDIP	2.5	3.5	3.5	3.5	pF	CIN
	Plastic DIP	1.25	2.0	2.0	2.0	pF	CIN
output voltage range	no load	4.0	3.6	3.8	3.8	V	VO
	R_L=100Ω	+3.8,-2.5	+3.0,-1.2	+3.6,-2.0	+3.6,-2.5	V	VOL
	R_L=100Ω , 0°C		+3.0,-1.6			V	VOL
output current		+60,-30	+40,-12	+40,-20	+40,-30	mA	IO
	0°C		+40,-16			mA	IO

Min/max ratings are based on product characterization and simulation. Individual parameters are tested as noted. Outgoing quality levels are determined from tested parameters.

Absolute Maximum Ratings

V_{cc}	±7.0V
I_{out} output is short circuit protected to ground, but maximum reliability will be maintained if I_{out} does not exceed...	36mA
input voltage	±V_{cc}
maximum junction temperature	+175°C
operating temperature range	
AJ/AI	-40°C to +85°C
A8/AM/AL	-55°C to +125°C
storage temperature range	-65°C to +150°C
lead temperature (soldering 10 sec)	+300°C

Miscellaneous Ratings

Notes:

*	AJ,AI	: 100% tested at +25°C, sample +85°C.
†	AJ	: Sample tested at +25°C.
†	AI	: 100% tested at +25°C.
*	A8	: 100% tested at +25°C, -55°C, +125°C
†	A8	: 100% tested at +25°C, sample at -55°C, +125°C.
*	AL,AM	: 100% wafer probe tested at +25°C to +25°C specifications.

(note 1) : Gain flatness tests are performed from 0.1MHz

Single Supply Electrical Characteristics (V_{CC}=+3V or V_{CC}=+5V, -V_{EE}=0V, T_A=+25°C, R_L = 100Ω, unless noted)

PARAMETERS	CONDITIONS	V_{CC}=3V	V_{CC}=5V	UNITS
FREQUENCY DOMAIN RESPONSE				
-3dB bandwidth	V_{out} < 0.5V_{pp}	30	90	MHz
	V_{out} < 2.0V_{pp}		35	MHz
gain flatness	V_{out} < 0.5V_{pp}			
flatness	DC to 30MHz	3	0.3	dB
peaking	DC to 200MHz	0	0	dB
rolloff	DC to 60MHz		1.5	dB
TIME DOMAIN RESPONSE				
rise and fall time	0.5V step	13.9	4.7	ns
	2.0V step		13.5	ns
overshoot	0.5V step	0	0	%
slew rate	0.5V step	35	200	V/µs
DISTORTION AND NOISE RESPONSE				
2nd harmonic distortion	0.5V_{pp},20MHz	-32		dBc
	1.0V_{pp},20MHz		-37	dBc
3rd harmonic distortion	0.5V_{pp},20MHz	-29		dBc
	1.0V_{pp},20MHz		-43	dBc
STATIC DC PERFORMANCE				
small-signal gain	AC-coupled	0.89	0.94	V/V
supply current	R_L= ∞	0.75	1.6	mA
MISCELLANEOUS PERFORMANCE				
output voltage range	R_L= ∞	1.5	2.8	V_{pp}
	R_L=100Ω	1.1	2.6	V_{pp}

Operation
The CLC109 is a low-power, high-speed unity-gain buffer. It uses a closed-loop topology which allows for accuracy not usually found in high-speed buffers. A closed-loop design provides high accuracy and low output impedance through a wide bandwidth.

Single Supply Operation
Although the CLC109 is specified to operate from split ±5V power supplies, there is no internal ground reference that prevents operation from a single voltage power supply. For single supply operation the input signal should be biased at a DC value of ½V_{CC}. This can be accomplished by AC coupling and rebiasing as shown in the "Typical Application" illustrations on the front page.

The above electrical specifications provide typical performance specifications for the CLC109 at 25°C while operating from a single +3V or a single +5V power supply.

Printed Circuit Layout and Supply Bypassing
As with any high-frequency device, a good PCB layout is required for optimum performance. This is especially important for a device as fast as the CLC109.

To minimize capacitive feedthrough, pins 2, 3, 6, and 7 should be connected to the ground plane, as shown in Figure 1. Input and output traces should be laid out as transmission lines with the appropriate termination resistors very near the CLC109. On a 0.065 inch epoxy PCB material, a 50Ω transmission line (commonly called stripline) can be constructed by using a trace width of 0.1" over a complete ground plane.

Figure 1 shows recommended power supply bypassing.

Parasitic or load capacitance directly on the output of the CLC109 will introduce additional phase shift in the device.

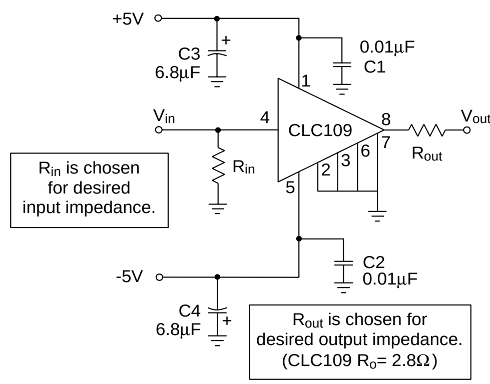


Figure 1: Recommended circuit & evaluation board schematic

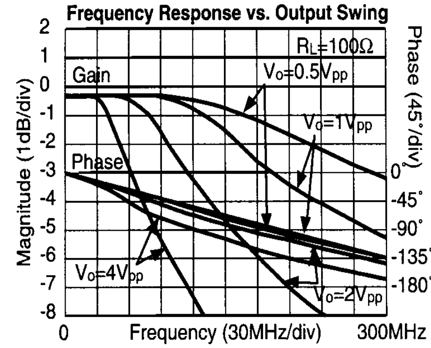
This phase shift can decrease phase margin and increase frequency response peaking. A small series resistor inserted between pin 6 and the capacitance effectively decouples this effect. The graphs on the following page illustrate the required resistor value and the resulting performance vs. capacitance.

Precision buffed resistors (PRP8351 series from Precision Resistive Products), which have low parasitic reactances, were used to develop the data sheet specifications. Precision carbon composition resistors or standard spirally-trimmed RN55D metal film resistors will work, though they may cause a slight degradation of ac performance due to their reactive nature at high frequencies.

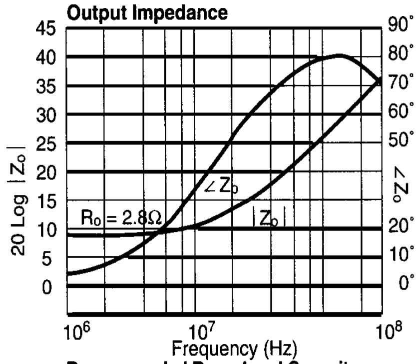
Evaluation Boards
Evaluation boards are available from Comlinear as part #730012 (DIP) and #730045 (SOIC). This board was used in the characterization of the device and provides optimal performance. Designers are encouraged to copy these printed circuit board layouts for their applications.

Typical Performance Characteristics (T_A = +25°C, V_{cc} = ± 5V, R_L = 100Ω unless specified)

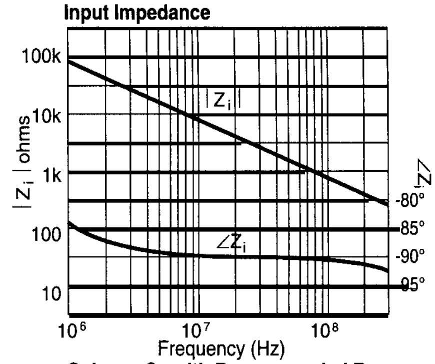
Frequency Response vs. Output Swing



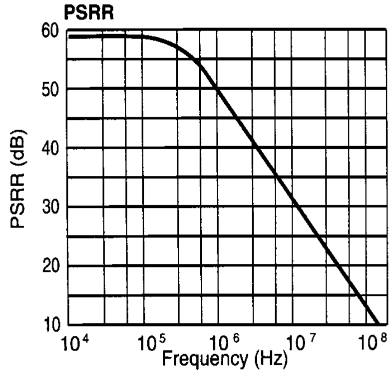
Output Impedance



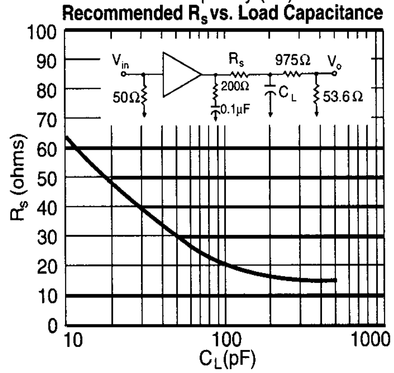
Input Impedance



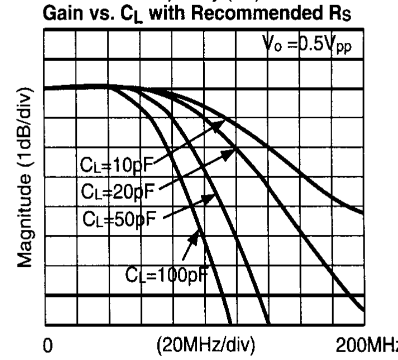
PSRR



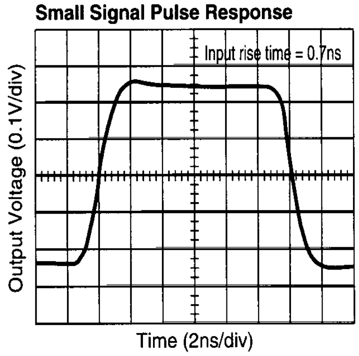
Recommended R_s vs. Load Capacitance



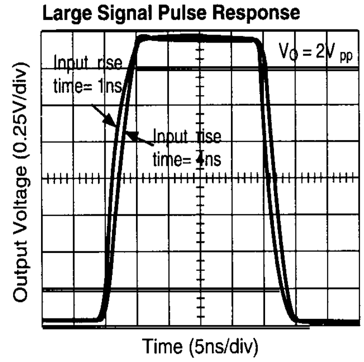
Gain vs. C_L with Recommended Rs



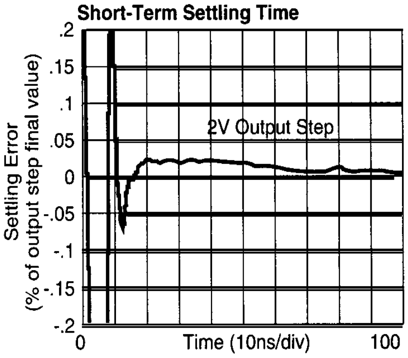
Small Signal Pulse Response



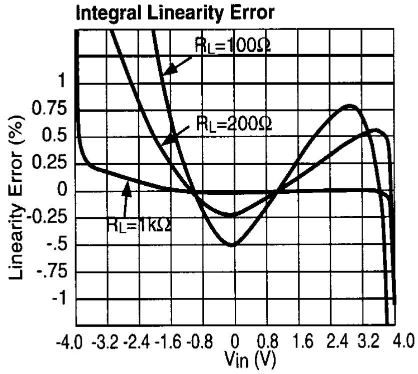
Large Signal Pulse Response



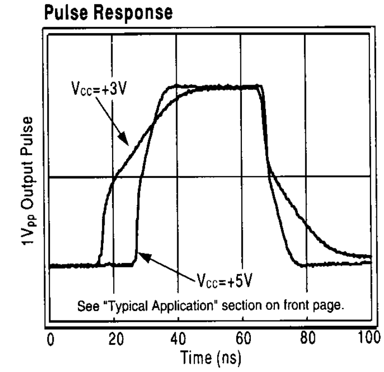
Short-Term Settling Time



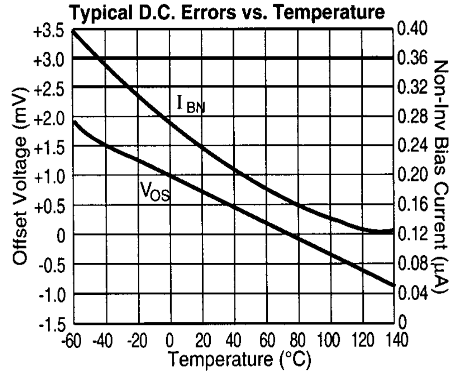
Integral Linearity Error



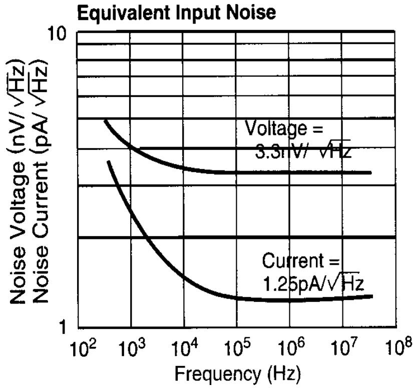
Pulse Response



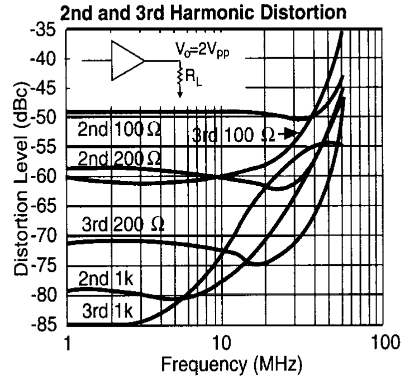
Typical D.C. Errors vs. Temperature



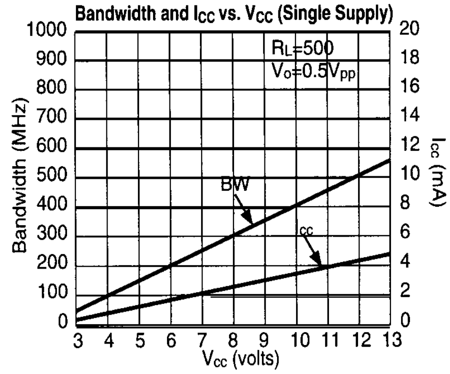
Equivalent Input Noise



2nd and 3rd Harmonic Distortion



Bandwidth and I_{CC} vs. V_{CC} (Single Supply)



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